

Diode

Emitter Controlled 4 Medium Power Technology IDC73D120T8M

**Data Sheet** 

Industrial Power Control



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# **Diode Chip in Emitter Controlled 4 Medium Power Technology**

### Features:

- 1200V Emitter Controlled 4 technology 110µm chip
- Soft, fast switching
- Low reverse recovery charge
- Small temperature coefficient

#### Recommended for:

• Low / medium power modules

# **Applications:**

• Low / medium power drives



Chip Type	<b>V</b> <sub>R</sub>	<b>I</b> Fn	Die Size	Package
IDC73D120T8M	1200V	150A	9.00mm x 8.15mm	Sawn on foil

#### **Mechanical Parameters**

Die size		9.00 x 8.15		
Area total		73.35 mr		
Anode pad size		See chip drawing		
Silicon thickness		110	μm	
Wafer size		200	mm	
Maximum possible chi	ps per wafer	358		
Passivation frontside		Photoimide		
Pad metal		3.2µm AlSiCu		
Backside metal		Ni Ag – system  To achieve a reliable solder connection it is strongly recommended not to consume the Ni layer completely during production process		
Die bond		Electrically conductive epoxy glue and soft solder		
Wire bond		AI, ≤500μm		
Reject ink dot size (va	ject ink dot size (valid for inked delivery form only) Ø 0.65mm; max 1.2mm			
Storage environment (<12 months)	for original and sealed MBB bags	Ambient atmosphere air, temperature 17°C – 2		
	for open MBB bags	Acc. IEC 62258-3; Section 9.4 Storage Environme		

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#### **Maximum Ratings**

In general, from reliability and lifetime point of view, the lower the operation junction temperature and/or the applied voltage, the greater the expected lifetime of any semiconductor device.

Not subject to production test, specified by design.

Parameter	Symbol	Value	Unit
Repetitive peak reverse voltage, T <sub>vj</sub> =25°C	<b>V</b> RRM	1200	V
Continuous forward current, limited by $T_{\rm vj\;max}$ <sup>1</sup>	<i>l</i> F	-	_
Maximum repetitive forward current, $t_p$ limited by $T_{vj \text{ max}}$	<b>I</b> FRM	300	A
Junction temperature	<b>T</b> vj	-40+175	°C
Operating junction temperature	T <sub>vj op</sub>	-40+150	°C

## Static Characteristics (tested on wafer), Tvj=25°C

Parameter	Symbol	Conditions	Value			Unit
rarameter	Symbol Conditions		min.	typ.	max.	Oilit
Reverse leakage current	<i>I</i> <sub>R</sub>	V <sub>R</sub> =1200V	-	-	26	μA
Cathode-anode breakdown voltage	$V_{BR}$	I <sub>R</sub> =0.25mA	1200	-	-	V
Forward voltage drop	V <sub>F</sub>	<i>I</i> <sub>F</sub> =45A	1.03	1.25	1.37	

#### **Electrical Characteristics**

Not subject to production test, specified by design.

Parameter		Symbol Conditions	Conditions	Value			Unit
			min.	typ.	max.	Onit	
Forward voltage	T <sub>vj</sub> =25°C	$V_{F}$	L-150A	1.35	1.70	2.05	\/
drop	<i>T</i> <sub>vj</sub> =150°C	VF	<i>I</i> <sub>F</sub> =150A	-	1.65	-	V

## **Further Electrical Characteristics**

Switching characteristics and thermal properties are depending strongly on module design and mounting technology and can therefore not be specified for a bare die.

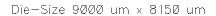
Application example	FS150R12KT4	Rev. 2.1
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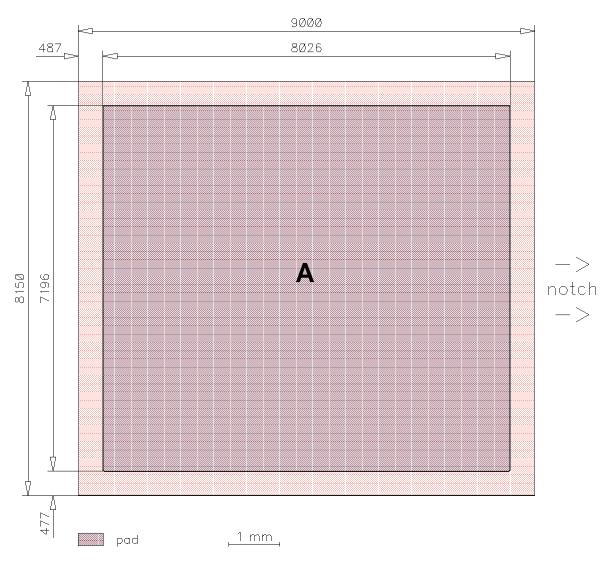
<sup>&</sup>lt;sup>1</sup> Depending on thermal properties of assembly.

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# **Chip Drawing**





## A = Anode pad



### **Bare Die Product Specifics**

Test coverage at wafer level cannot cover all application conditions. Therefore it is recommended to test all characteristics which are relevant for the application at package level, including RBSOA and SCSOA.

### **Description**

AQL 0.65 for visual inspection according to failure catalogue

Electrostatic Discharge Sensitive Device according to MIL-STD 883

### **Revision History**

Revision	Subjects (major changes since last revision)	Date
2.0	Final data sheet	22.08.2016
2.1	Editorial changes	09.04.2021

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